

QDLASER

QLD1x6P-xxD0 series

1 μ m 400mW DFB Laser BFY Module under 1-10 ns Pulsed Operation

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1. DESCRIPTION

The QLD1x6P-xxD0 is a high power 1 μ m-wavelength range distributed feedback (DFB) laser under 1-10 ns pulsed operation for use in seeder for fiber lasers and sensing applications. The laser is assembled into a 14-pin butterfly package with an optical isolator, a monitor PD and a thermo-electric cooler.

2. FEATURES

- Single longitudinal mode operation
- High peak output power of 400mW under pulsed operation
- 1-10 ns pulse width available
- Fiber-pigtailed 14-pin butterfly package with a TEC
- Optical isolator integration
- Polarization maintaining fiber integration

3. APPLICATIONS

- Seeder for fiber lasers
- Sensing

4. ABSOLUTE MAXIMUM RATINGS

| PARAMETER | SYMBOL | RATING | UNIT |
|--------------------------------------|----------------|-----------|--------------|
| Optical Output power (CW) | P_f | 50 | mW |
| LD Forward Current (CW) | I_f | 250 | mA |
| Peak Output power (Pulse 10 ns/1MHz) | P_{f_pulse} | 600 | mW |
| LD Peak Current (Pulse 10 ns/1MHz) | I_{f_pulse} | 2 | A |
| LD Reverse Voltage | V_{RLD} | 2 | V |
| TEC Drive Current | I_{TEC} | 2 | A |
| TEC Drive Voltage | V_{TEC} | 4.3 | V |
| Operation Temperature | T_c | 0 to 60 | $^{\circ}$ C |
| Storage Temperature | T_{stg} | -40 to 85 | $^{\circ}$ C |
| Lead Soldering Temperature (10 s) | T_{sld} | 260 | $^{\circ}$ C |

5. OPTICAL AND ELECTRICAL CHARACTERISTICS

(T_{LD} = 25°C, unless otherwise specified)

| PARAMETER | SYMBOL | TEST CONDITION | MIN | TYP | MAX | UNIT |
|----------------------------------------|---------------------|---------------------------------------|-----------------------|------------------|-----------------------|------|
| Peak Wavelength | λ_p | CW, P _f =30 mW | λ_p-5 (*2) | λ_p (*1) | λ_p+5 (*2) | nm |
| Temperature Coefficient of λ_p | $d\lambda_p/dT$ | CW / Pulsed | - | 0.08 | - | nm/K |
| Threshold Current | I _{th} | CW / Pulsed | - | 15 | 30 | mA |
| CW Fiber Output Power | P _f | CW | 30 | - | - | mW |
| CW Operation Voltage | V _{op} | CW, P _f =30 mW | - | 1.8 | - | V |
| Pulsed Peak Output Power | P _{f_peak} | Pulsed, I _{f_peak} =1.6 A | 400 | 500 | - | mW |
| Pulsed Averaged Output Power | P _{f_ave} | Pulsed 1 ns/100kHz/1.6A | 40 | - | - | μW |
| | | Pulsed 10 ns/100kHz/1.6A | 400 | - | - | μW |
| Pulse Width | t _{pw} | Pulsed | 1 | - | 10 | ns |
| Duty Cycle | D.C. | Pulsed | - | - | 1(*3) | % |
| Sidemode Suppression Ratio | SMSR | CW, P _f =30 mW | 30 | 40 | - | dB |
| | | Pulsed 1ns/100kHz | 25 | 30 | - | dB |
| Spectral line width | $\Delta\lambda$ | Pulsed 1ns/100kHz, @-3dB from peak | | 0.04 | | nm |
| Polarization Extinction Ratio | PER | CW | 15 | 20 | - | dB |
| Monitor PD Current | I _m | CW, P _f =30 mW | - | 300 | - | μA |
| Thermistor Resistance | R _{th} | T _{LD} = 25°C, B=3900K | 9.5 | 10 | 10.5 | kΩ |

(*1) Available peak wavelength is from 1024 to 1180 nm.

(*2) Tighter wavelength tolerance is available as an option.

(*3) Higher duty cycle is available with proper adjustment of a peak current. Please ask QDL for more detail.

6. PRODUCT PART NUMBER

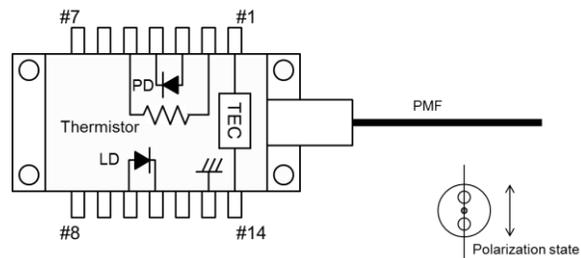
| Part Number | Fiber Type | Fiber Diameter | Connector |
|-----------------|-----------------------------------|----------------|-----------|
| QLD1x6P-xxD0 | Polarization maintaining fiber | 900um | FC/APC |
| QLD1x6P-xxD0-11 | | 250um | Ferrule |

Examples of product name

| Peak Wavelength (nm) | Part Number |
|----------------------|--------------|
| 1030 | QLD106P-30D0 |
| 1053 | QLD106P-53D0 |
| 1064 | QLD106P-64D0 |
| 1083 | QLD106P-83D0 |
| 1120 | QLD116P-20D0 |
| 1180 | QLD116P-80D0 |

8. PIN CONFIGURATION

| No. | Description | No. | Description |
|-----|-------------|-----|---------------|
| 1 | TEC (+) | 8 | NC |
| 2 | Thermistor | 9 | NC |
| 3 | PD Anode | 10 | Laser Anode |
| 4 | PD Cathode | 11 | Laser Cathode |
| 5 | Thermistor | 12 | NC |
| 6 | NC | 13 | Case Ground |
| 7 | NC | 14 | TEC (-) |



9. NOTICE

• Safety Information

This product is classified as Class 3B laser product, and complies with 21 CFR Part 1040.10.

Please do not take a look at laser lighting in operations since laser devices may cause troubles to human eyes.

Please do not eat, burn, break and make chemical process of the products since they contain GaAs material.

• Handling products

Semiconductor lasers are easily damaged by external stress such as excess temperature and ESD.

Please pay attention to handling products, and use within range of maximum ratings.

QD Laser takes no responsibility for any failure or unusual operation resulting from improper handling, or unusual physical or electrical stress.

• RoHS

This product conforms to RoHS compliance related EU Directive 2011/65/EU.

| | |
|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------|
| <p>DANGER</p> | <p>LASER DIODE</p> |
| <p>INVISIBLE LASER RADIATION AVOID DIRECTION EXPOSURE TO BEAM</p> <p>MAXIMUM OUTPUT 1 W WAVELENGTH 1000~1200 nm CLASS IV LASER PRODUCT</p> | <p>AVOID EXPOSURE-Invisible Laser Radiation is emitted from this aperture.</p> |
| <p>This product complies with 21 CFR Part 1040.10 and 1040.11 except for deviations pursuant to Laser Notice No.50, dated June 24, 2007</p> <p>QD Laser, Inc. 1-1 Minamiwataridacho, Kawasaki-ku, Kawasaki, Kanagawa, 210-0855 Japan</p> | |

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